

## 描述 / Descriptions

PDFN5×6 封装 N 沟道场效应管。

N-Channel MOSFET in a PDFN5×6 Plastic Package.

## 特征 / Features

$V_{DS}(V)=60\text{ V}$       $I_D=158\text{ A}$

$R_{DS(ON)}@10\text{V}\leq 2.0\text{ m}\Omega(\text{Typ.}1.8\text{ mR})$

$R_{DS(ON)}@4.5\text{V}\leq 3.0\text{ m}\Omega(\text{Typ.}2.5\text{ mR})$

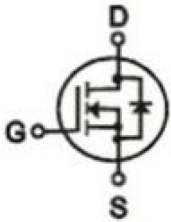
符合 AEC-Q101 标准高可靠性要求，无卤产品。Qualified to AEC-Q101 Standards for High Reliability, HF Product.

## 用途 / Applications

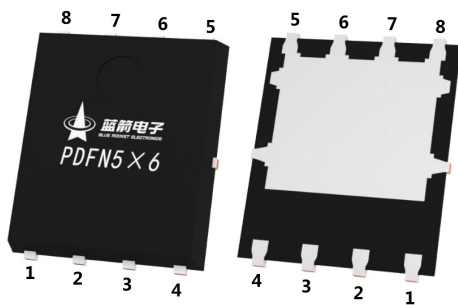
次级侧同步整流，DC-DC 变换器，电机控制，负载切换，满足汽车应用的严格要求。

Secondary Side Synchronous Rectification, DC-DC Converter, Motor Control, Load Switching, Meet the stringent requirements of automotive applications.

## 内部等效电路 / Equivalent Circuit



## 引脚排列 / Pinning



PIN1、2、3: S     PIN4: G     PIN5、6、7、8: D

## 印章代码 / Marking

见印章说明。

See Marking Instructions.

**极限参数 / Absolute Maximum Ratings( $T_a=25^{\circ}\text{C}$ )**

参数 Parameter	符号 Symbol	数值 Rating	单位 Unit
Drain-Source Voltage	$V_{DS}$	60	V
Continuous Drain Current	$I_D(T_c=25^{\circ}\text{C})$	158	A
Pulsed Drain Current	$I_{DM}$	316	A
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Power Dissipation	$P_D(T_c=25^{\circ}\text{C})$	90	W
Avalanche energy(L=0.5mH)	$E_{AS}$	380	mJ
Avalanche Current(L=0.5mH)	$I_{AS}$	30.8	A
Junction and Storage Temperature Range	$T_j, T_{stg}$	-55 to 150	$^{\circ}\text{C}$
Maximum Junction-to-Ambient	$t \leq 10\text{s}$	$R_{\theta JA}$	$^{\circ}\text{C}/\text{W}$
	Steady-State		
Maximum Junction-to-Case	Steady-State	$R_{\theta JC}$	1.39

**电性能参数 / Electrical Characteristics( $T_a=25^{\circ}\text{C}$ )**

参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0\text{V}$ $I_D=250\mu\text{A}$	60	65		V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=60\text{V}$ $V_{GS}=0\text{V}$			1	$\mu\text{A}$
Gate-Body Leakage Current Forward	$I_{GSS}$	$V_{GS}=\pm 20\text{V}$ $V_{DS}=0\text{V}$			$\pm 100$	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\mu\text{A}$	1	1.6	2.5	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10\text{V}$ $I_D=20\text{A}$		1.8	2.5	m $\Omega$
		$V_{GS}=4.5\text{V}$ $I_D=10\text{A}$		2.4	3.5	
Forward On Voltage	$V_{SD}$	$V_{GS}=0\text{V}$ $I_S=1\text{A}$			1.2	V
Gate resistance	$R_g$	$f=1\text{MHz}$		1.0		$\Omega$
Input Capacitance	$C_{iss}$	$V_{DS}=25\text{V}$ $V_{GS}=0\text{V}$ $f=1.0\text{MHz}$		6700		pF
Output Capacitance	$C_{oss}$			1400		
Reverse Transfer Capacitance	$C_{rss}$			70		
Total Gate Charge	$Q_{g(10V)}$	$V_{GS}=10\text{V}$ , $V_{DS}=30\text{V}$ , $I_D=20\text{A}$		60		nC
Total Gate Charge	$Q_{g(4.5V)}$			23		
Gate Source Charge	$Q_{gs}$			16		
Gate Drain Charge	$Q_{gd}$			3		

## 电性能参数 / Electrical Characteristics(Ta=25°C)

参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V$ $V_{DS}=20V$ $R_L=1\ \Omega$ $R_{GEN}=3\ \Omega$		13		ns
Turn-On Rise Time	$t_r$			4		
Turn-Off Delay Time	$t_{d(off)}$			47		
Turn-Off Fall Time	$t_f$			6.5		

电参数曲线图 / Electrical Characteristic Curve

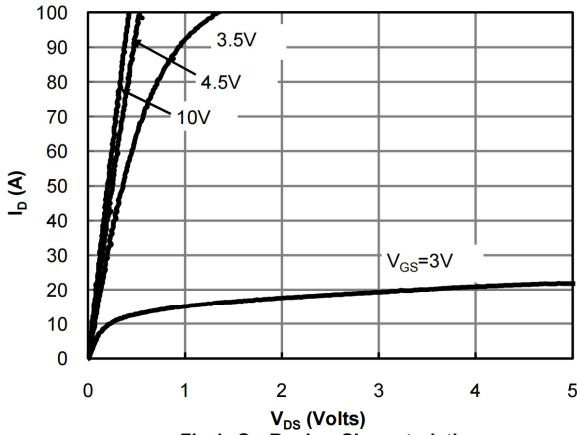


Fig 1: On-Region Characteristics

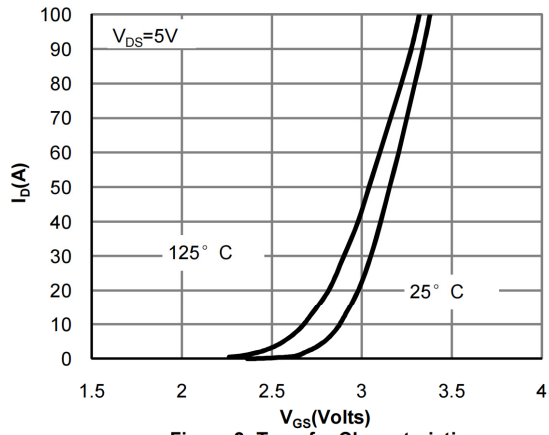


Figure 2: Transfer Characteristics

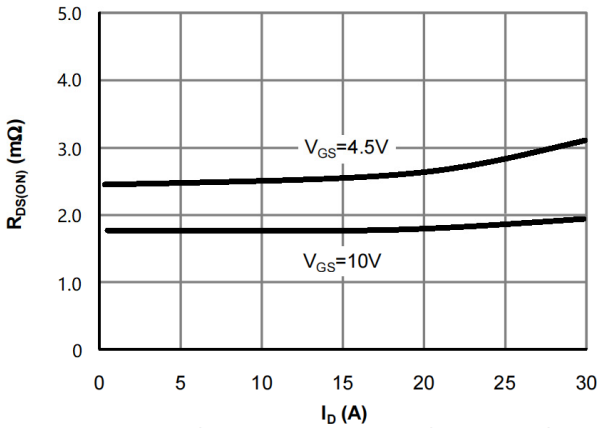


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

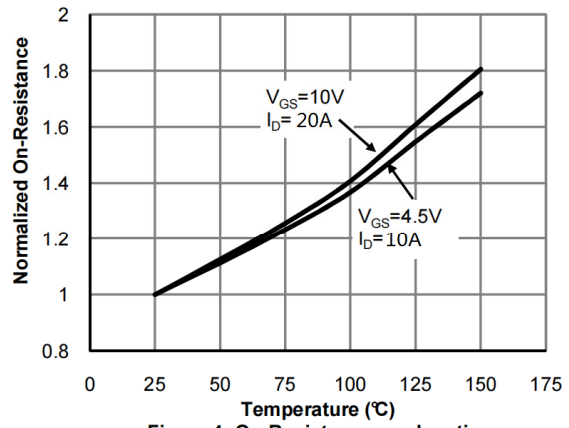


Figure 4: On-Resistance vs. Junction Temperature

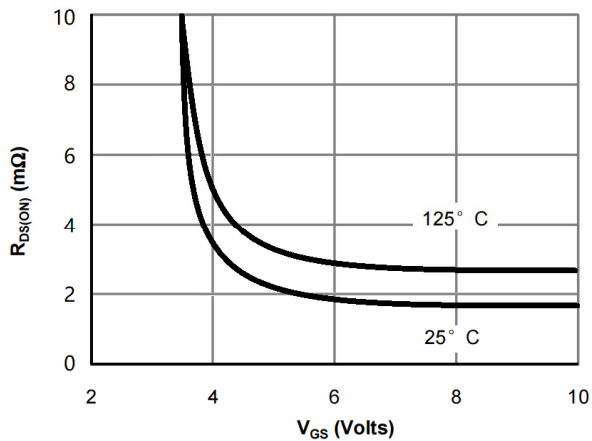


Figure 5: On-Resistance vs. Gate-Source Voltage

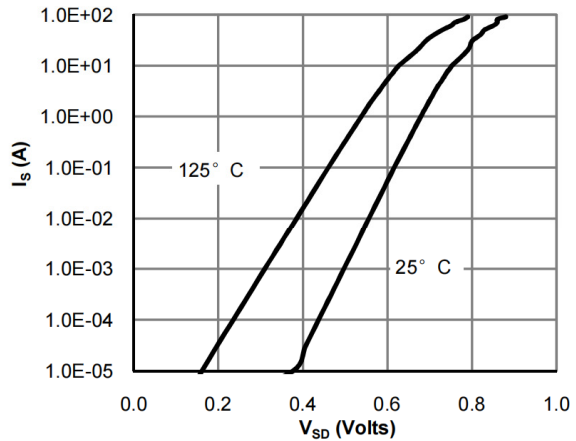
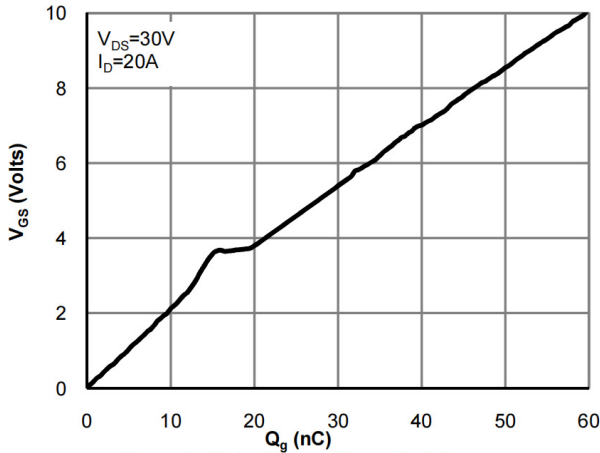
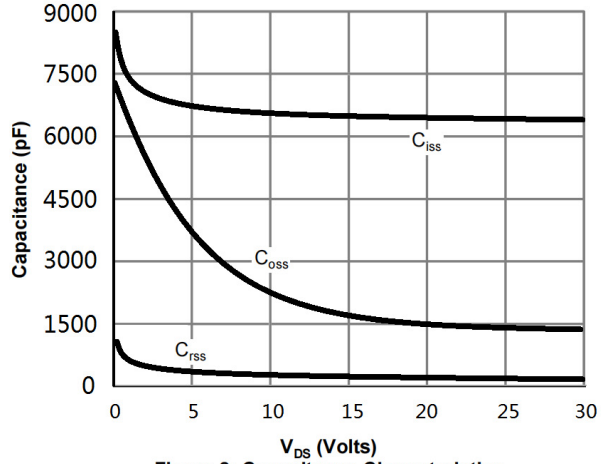


Figure 6: Body-Diode Characteristics

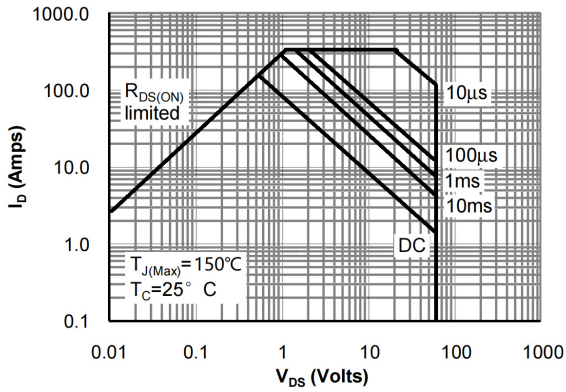
**电参数曲线图 / Electrical Characteristic Curve**



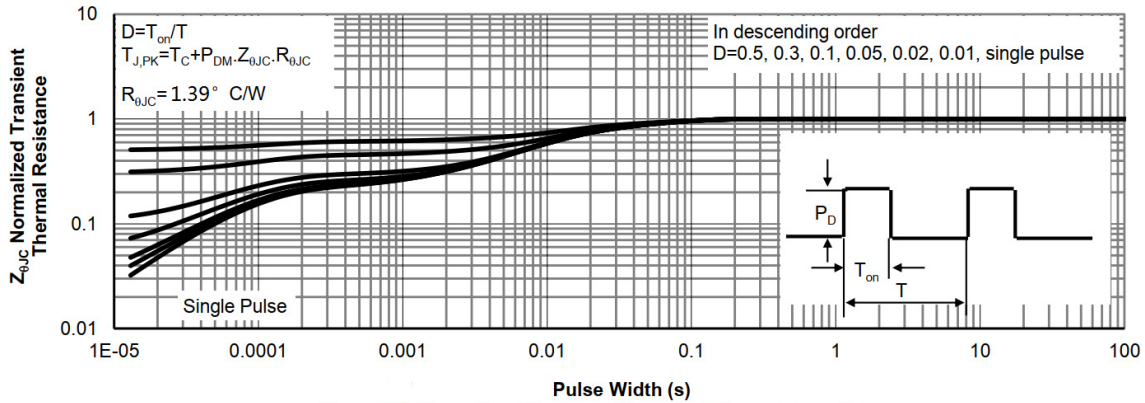
**Figure 7: Gate-Charge Characteristics**



**Figure 8: Capacitance Characteristics**



**Figure 9: Maximum Forward Biased Safe Operating Area**

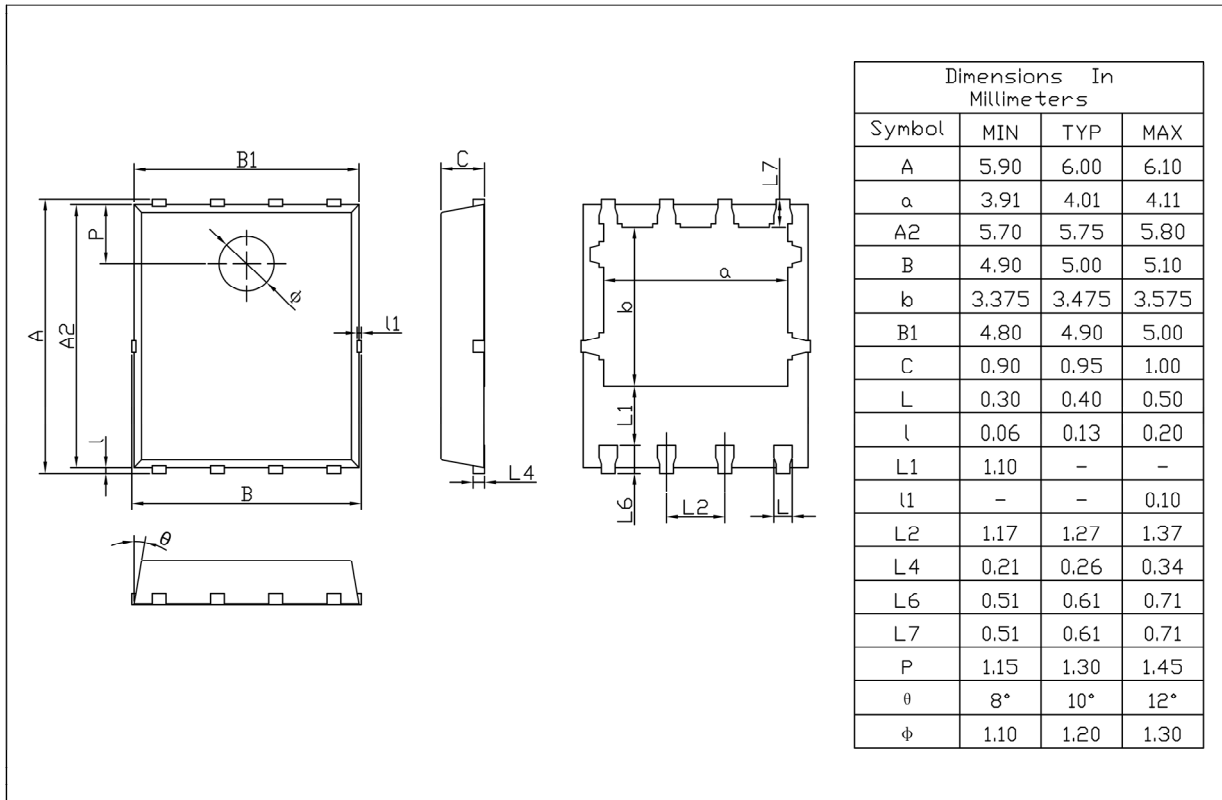


**Figure 10: Normalized Maximum Transient Thermal Impedance**

**外形尺寸图 / Package Dimensions**

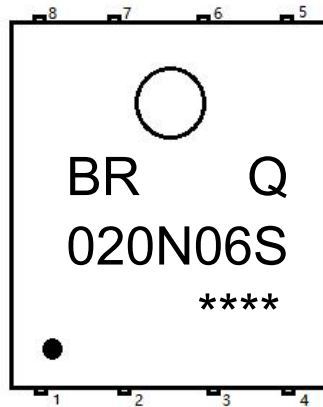
PDFN5×6

Unit:mm



Rev.01 202209

**印章说明 / Marking Instructions**



说明：

BR： 为公司代码

Q： 为汽车无卤产品标识

020N06S： 为型号代码

\*\*\*\*： 为生产批号代码，随生产批号变化

Note：

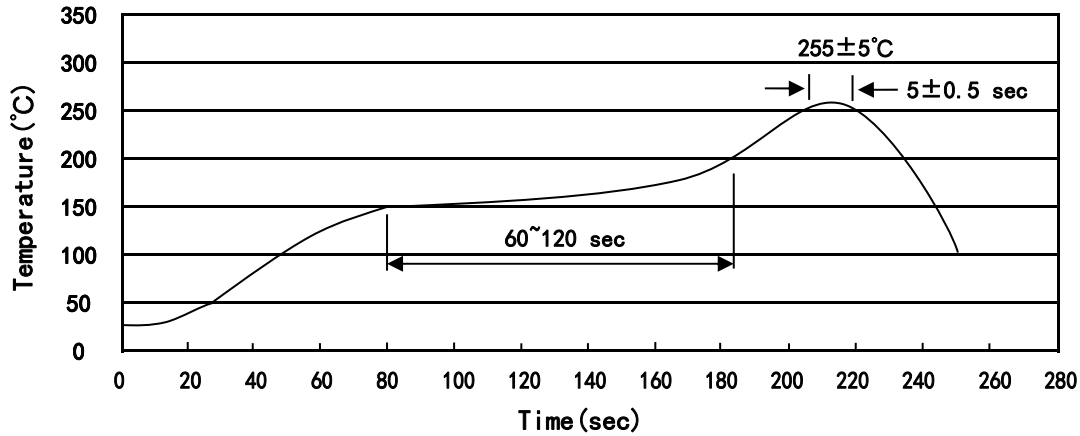
BR： Company Code

Q: Automobile halogen-free product Code

020N06S： Product Type Code

\*\*\*\*: Lot No. Code, code change with Lot No

**回流焊温度曲线图(无铅) / Temperature Profile for IR Reflow Soldering(Pb-Free)**



说明：

- 1、预热温度 150~200°C，时间 60~120sec;
- 2、峰值温度 255±5°C，时间持续为 5±0.5sec;
- 3、焊接制程冷却速度为 2~10°C/sec.

Note:

- 1.Preheating:150~200°C, Time:60~120sec.
- 2.Peak Temp.:255±5°C, Duration:5±0.5sec.
3. Cooling Speed: 2~10°C/sec.

**耐焊接热试验条件 / Resistance to Soldering Heat Test Conditions**

温度：260±5°C

时间：10±1 sec.

Temp.:260±5°C

Time:10±1 sec

**包装规格 / Packaging SPEC.**

卷盘包装 / REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm <sup>3</sup> )		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
PDFN5×6	5,000	2	10,000	6	60,000	13"×12	360×360×50	380×335×366

**使用说明 / Notices**